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80 V, 1 A NPN medium power transistors Rev. 9 — 25 October 2011

#### 1. **Product profile**

#### **1.1 General description**

NPN medium power transistor series in Surface-Mounted Device (SMD) plastic packages.

#### **Product overview** Table 1.

Type number <sup>[1]</sup>	Package	Package				
	NXP	JEITA	JEDEC			
BCP56	SOT223	SC-73	-	BCP53		
BCX56	SOT89	SC-62	TO-243	BCX53		
BC56PA	SOT1061	-	-	BC53PA		

[1] Valid for all available selection groups.

#### 1.2 Features and benefits

- High current
- Three current gain selections
- High power dissipation capability
- Exposed heatsink for excellent thermal and electrical conductivity (SOT89, SOT1061)
- Leadless very small SMD plastic package with medium power capability (SOT1061)
- AEC-Q101 gualified

### 1.3 Applications

- Linear voltage regulators
- Low-side switches
- Battery-driven devices
- Power management
- MOSFET drivers
- Amplifiers

#### 1.4 Quick reference data

#### Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	80	V
I <sub>C</sub>	collector current		-	-	1	А
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-	2	А
h <sub>FE</sub>	DC current gain	$V_{CE} = 2 \text{ V}; I_{C} = 150 \text{ mA}$	<u>[1]</u> 63	-	250	
	h <sub>FE</sub> selection -10	$V_{CE} = 2 \text{ V}; I_{C} = 150 \text{ mA}$	<u>[1]</u> 63	-	160	
	h <sub>FE</sub> selection -16	$V_{CE} = 2 \text{ V}; I_{C} = 150 \text{ mA}$	<u>[1]</u> 100	-	250	

[1] Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta = 0.02$ .



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### 2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
SOT223			
1	base		
2	collector		2,4
3	emitter		1
4	collector		3 sym016
SOT89			Symoro
1	emitter		
2	collector		2 J
3	base		31 sym042
SOT1061			
1	base		_
2	emitter	3	3
3	collector		1
		1   2   Transparent top view	sym021

### 3. Ordering information

Table 4. Order	ing inform	ation					
Type number <sup>[1]</sup>	Package						
	Name	Description	Version				
BCP56	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223				
BCX56	SC-62	plastic surface-mounted package; exposed die pad for good heat transfer; 3 leads	SOT89				
BC56PA	HUSON3	plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body $2 \times 2 \times 0.65$ mm	SOT1061				

[1] Valid for all available selection groups.

BCP56\_BCX56\_BC56PA

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### 4. Marking

Table 5.   Marking codes	
Type number	Marking code
BCP56	BCP56
BCP56-10	BCP56/10
BCP56-16	BCP56/16
BCX56	ВН
BCX56-10	ВК
BCX56-16	BL
BC56PA	AZ
BC56-10PA	ВК
BC56-16PA	BL

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### 5. Limiting values

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter	-	100	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	80	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	5	V
l <sub>C</sub>	collector current		-	1	А
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms	-	2	A
I <sub>B</sub>	base current		-	0.3	А
I <sub>BM</sub>	peak base current	single pulse; $t_p \le 1 \text{ ms}$	-	0.3	А
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	BCP56		<u>[1]</u> _	0.65	W
			[2]	1.00	W
			[3]	1.35	W
	BCX56		<u>[1]</u> _	0.50	W
			[2]	0.95	W
			<u>[3]</u>	1.35	W
	BC56PA		<u>[1]</u> _	0.42	W
			[2]	0.83	W
			[3]	1.10	W
			<u>[4]</u> _	0.81	W
			<u>[5]</u>	1.65	W
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

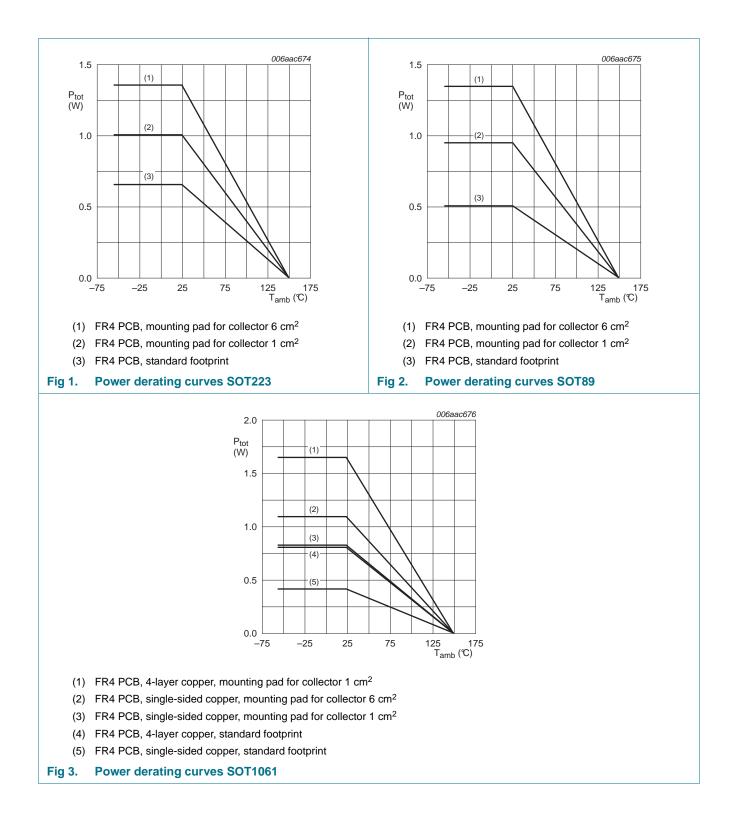
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

# BCP56; BCX56; BC56PA



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### 6. Thermal characteristics

Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air				
	BCP56		<u>[1]</u> -	-	192	K/W
			[2] _	-	125	K/W
			[3] _	-	93	K/W
	BCX56		<u>[1]</u> -	-	250	K/W
			[2] _	-	132	K/W
			[3] _	-	93	K/W
	BC56PA		<u>[1]</u> -	-	298	K/W
			[2] _	-	151	K/W
			[3] _	-	114	K/W
			<u>[4]</u> _	-	154	K/W
			[5] _	-	76	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point					
	BCP56		-	-	16	K/W
	BCX56		-	-	16	K/W
	BC56PA		-	-	20	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

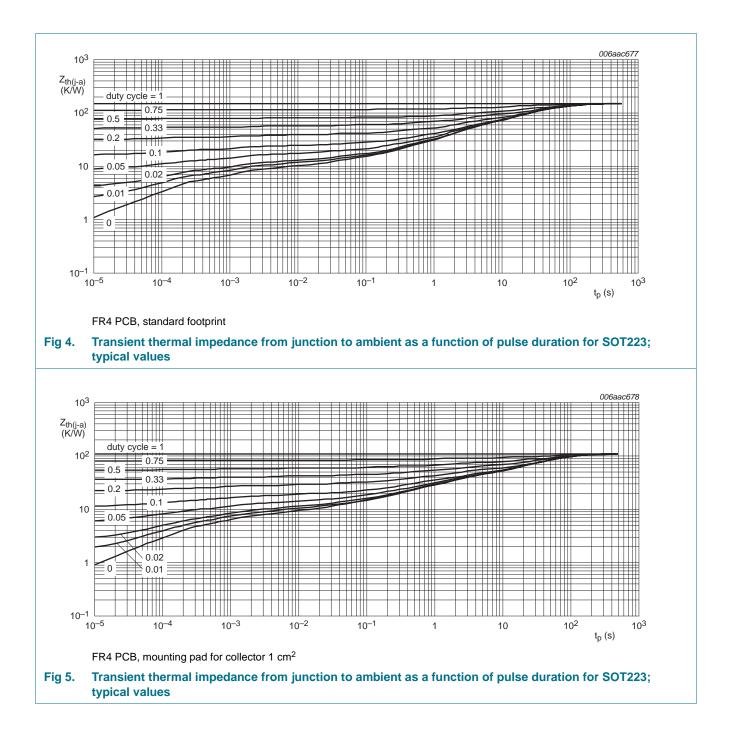
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

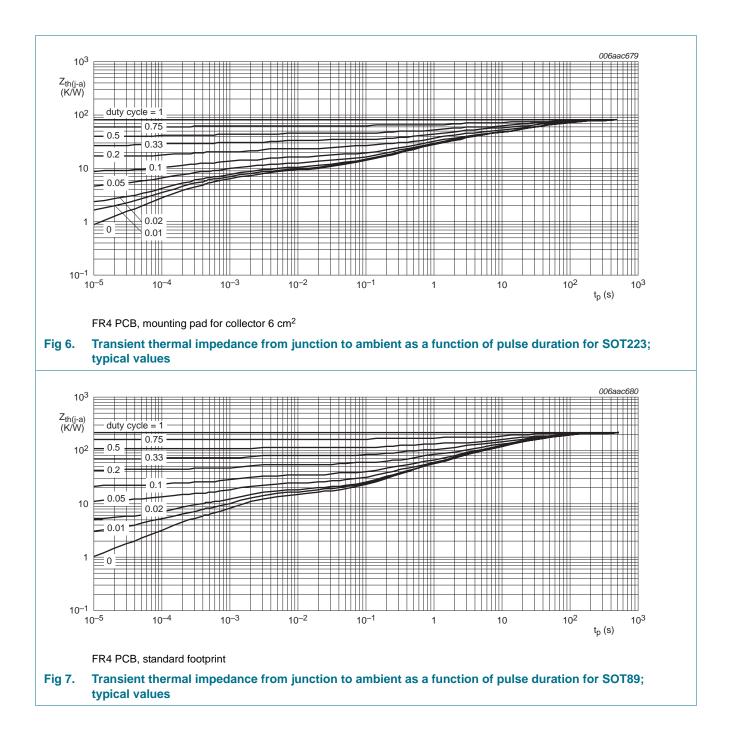
[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

[5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

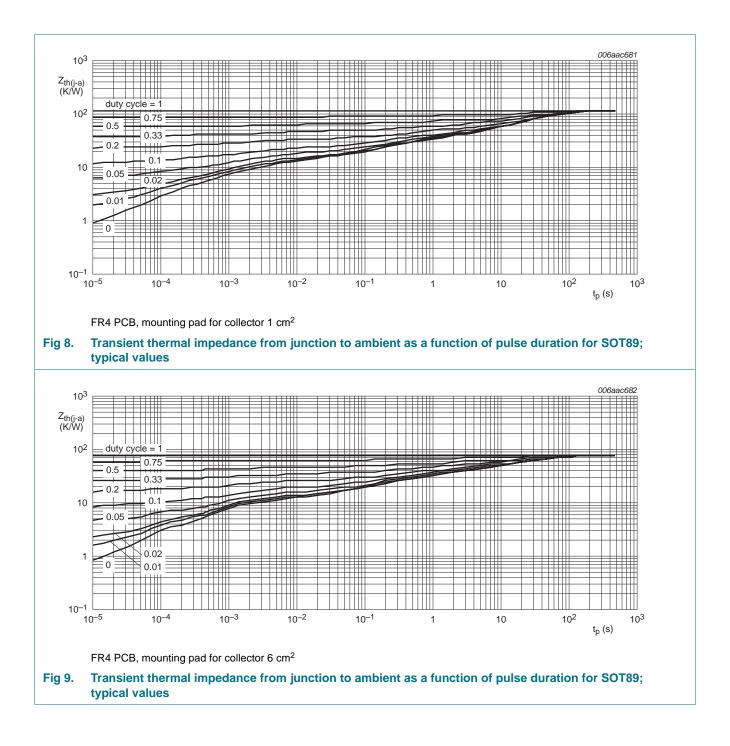
# BCP56; BCX56; BC56PA



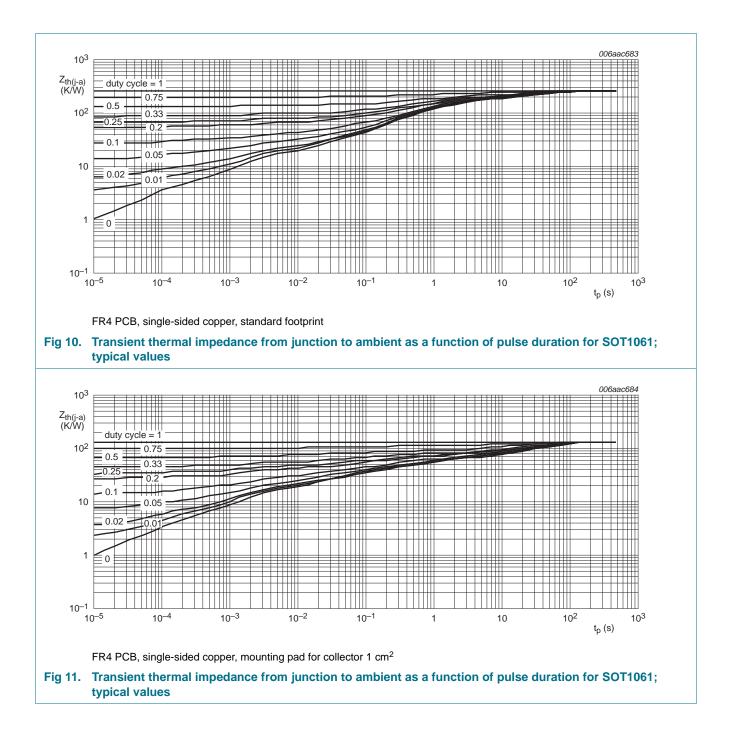
# BCP56; BCX56; BC56PA



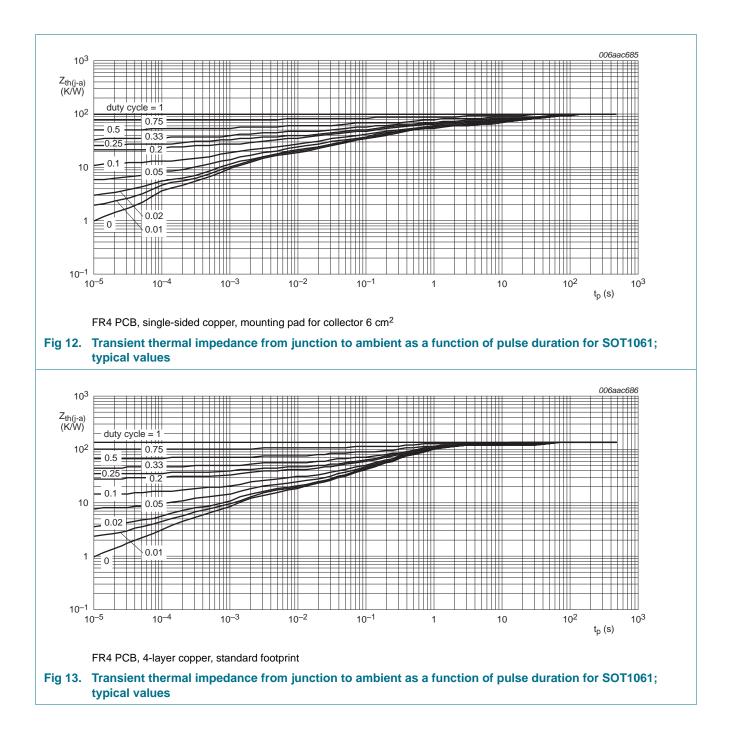
# BCP56; BCX56; BC56PA



# BCP56; BCX56; BC56PA

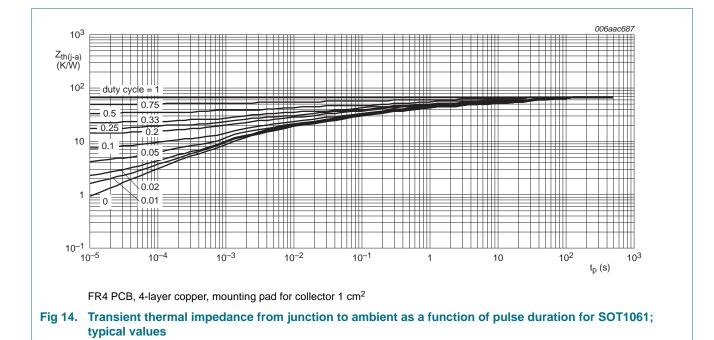


# BCP56; BCX56; BC56PA



# BCP56; BCX56; BC56PA

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### 7. Characteristics

### Table 8. Characteristics

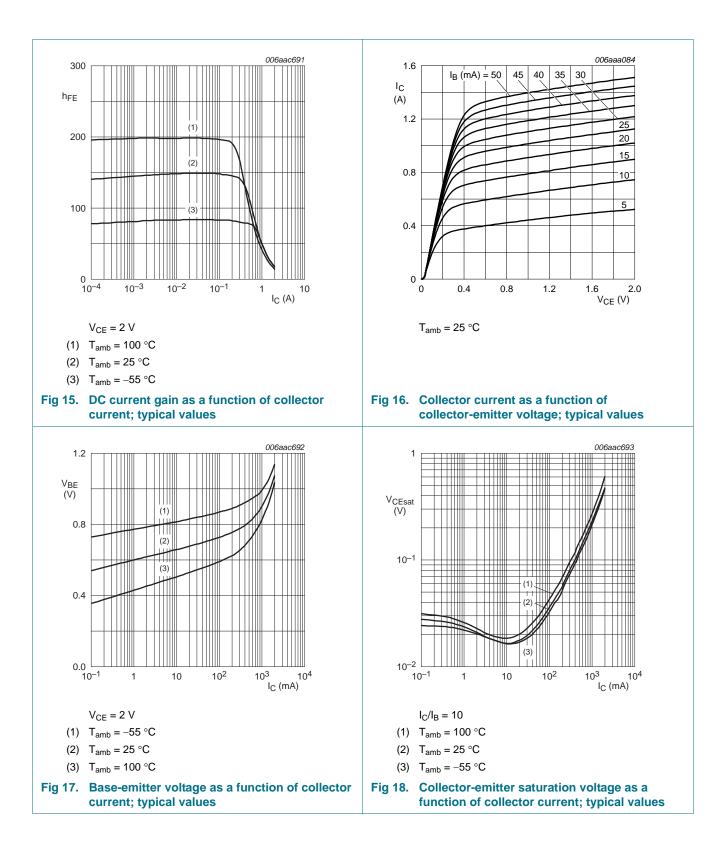
 $T_{amb} = 25 \ ^{\circ}C$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
I <sub>CBO</sub>	collector-base cut-off	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
	current	$\label{eq:VCB} \begin{array}{l} V_{CB} = 30 \ V; \ I_E = 0 \ A; \\ T_j = 150 \ ^\circC \end{array}$	-	-	10	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	100	nA
h <sub>FE</sub> DC current gain		$V_{CE} = 2 V$				
		$I_{\rm C} = 5  \rm{mA}$	<u>[1]</u> 63	-	-	
		I <sub>C</sub> = 150 mA	<mark>[1]</mark> 63	-	250	
	I <sub>C</sub> = 500 mA	<u>[1]</u> 40	-	-		
	DC current gain	$V_{CE} = 2 V$				
	h <sub>FE</sub> selection -10	I <sub>C</sub> = 150 mA	<u>[1]</u> 63	-	160	
	h <sub>FE</sub> selection -16	I <sub>C</sub> = 150 mA	<u>1</u> 100	-	250	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{\rm C}$ = 500 mA; $I_{\rm B}$ = 50 mA	<u>[1]</u> -	-	0.5	V
V <sub>BE</sub>	base-emitter voltage	$V_{CE} = 2 \text{ V}; \text{ I}_{C} = 500 \text{ mA}$	<u>[1]</u> -	-	1	V
C <sub>c</sub>	collector capacitance	$\label{eq:VCB} \begin{array}{l} V_{CB} = 10 \text{ V}; \text{ I}_{E} = \text{i}_{e} = 0 \text{ A}; \\ \text{f} = 1 \text{ MHz} \end{array}$	-	6	-	pF
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 50 mA; f = 100 MHz	100	180	-	MHz

[1] Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta = 0.02$ .

# BCP56; BCX56; BC56PA

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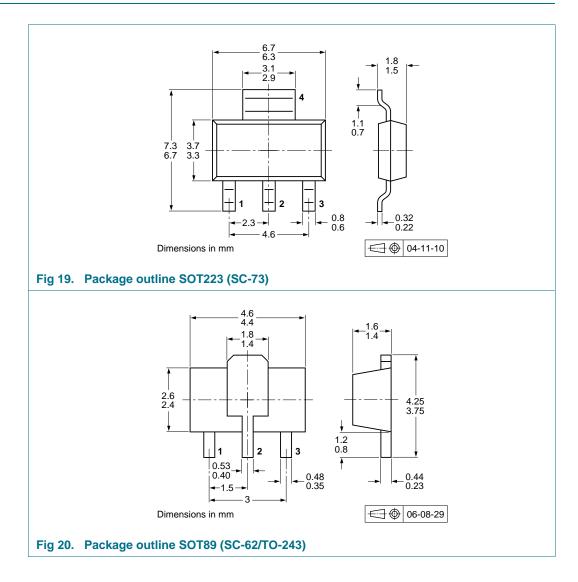
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### 8. Test information

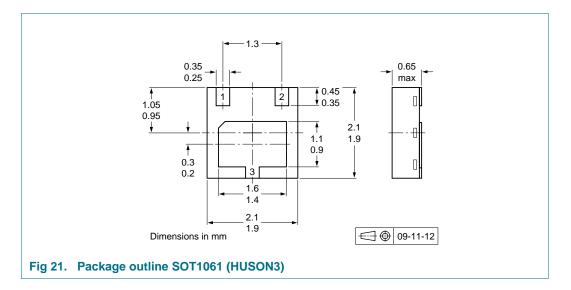
#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 9. Package outline



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### **10. Packing information**

#### Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Туре	Package Description			Packin	g quant	ity
number <sup>[2]</sup>				1000	3000	4000
BCP56	SOT223	8 mm pitch, 12 mm tape and reel		-115	-	-135
BCX56 SOT89		8 mm pitch, 12 mm tape and reel; T1	[3]	-115	-	-135
		8 mm pitch, 12 mm tape and reel; T3	[4]	-146	-	-
BC56PA	SOT1061	4 mm pitch, 8 mm tape and reel		-	-115	-

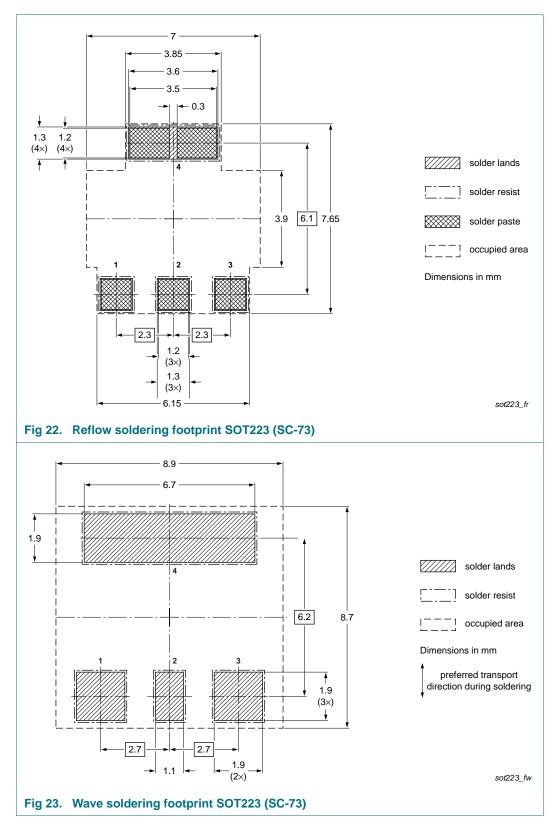
[1] For further information and the availability of packing methods, see <u>Section 14</u>.

[2] Valid for all available selection groups.

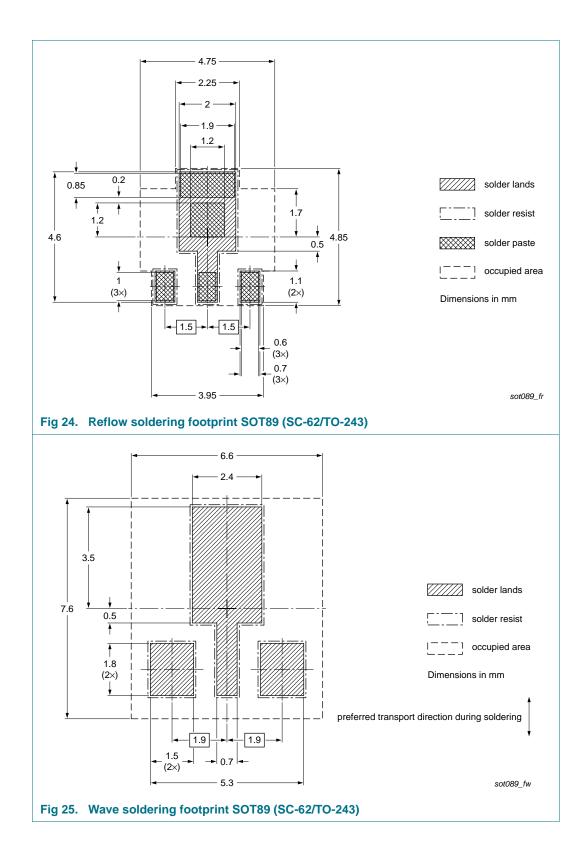
- [3] T1: normal taping
- [4] T3: 90° rotated taping

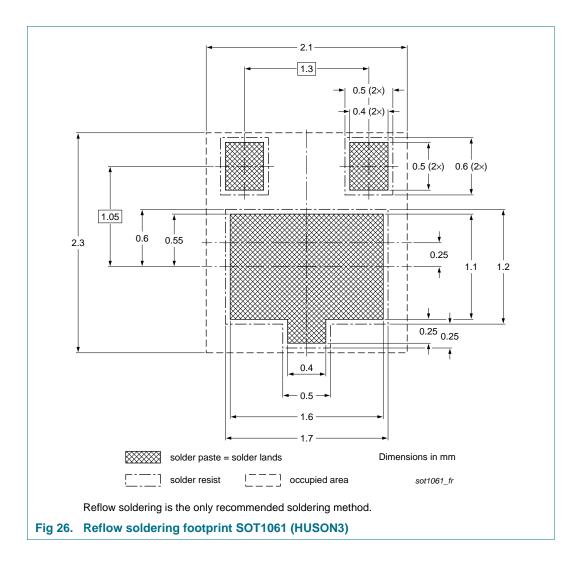
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### 11. Soldering



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### 12. Revision history

#### Table 10.Revision history

111025	Data sheet status Product data sheet	Change notice	Supersedes BC639_BCP56_BCX56 v.8			
		-	BC639 BCP56 BCX56 v.8			
Type numbe						
	r removed: BC639					
<ul> <li>Type number added: BC56PA, BC56-10PA and BC56-16PA</li> </ul>						
Section 1 "Pi	roduct profile": updated					
Section 2 "Pi	inning information": update	ed				
Table 6 and	2: updated according to late	test measurement	s			
Figure 1, 2, 4	<u>4, 5, 7</u> to <u>9, 15, 17</u> and <u>18</u> :	updated				
Figure 3, <u>6</u> , 1	10 to 14: added					
Section 8 "Te	est information": added					
Section 10 "	Packing information": upda	ated				
Section 11 "S	Soldering": added					
Section 13 "L	<u>egal information</u> : update	d				
070622	Product data sheet	-	BC639_BCP56_BCX56 v.7			
050308	Product data sheet	-	BC639_BCP56_BCX56 v.6			
050303	Product data sheet	CPCN2004050	BC635_637_639 v.4			
		29	BCP54_55_56 v.5			
			BCX54_55_56 v.4			
011010	Product specification	-	BC635_637_639 v.3			
030206	Product specification	-	BCP54_55_56 v.4			
011010	Product specification	-	BCX54_55_56 v.3			
	Section 2 "P Table 6 and Figure 1, 2, 4 Figure 3, 6, 7 Section 8 "Te Section 10 "I Section 11 "S Section 13 "I 070622 050308 050303	Section 2 "Pinning information": updateTable 6and 7: updated according to latFigure 1, 2, 4, 5, 7 to 9, 15, 17 and 18:Figure 3, 6, 10 to 14: addedSection 8 "Test information": addedSection 10 "Packing information": updateSection 11 "Soldering": addedSection 13 "Legal information": update070622Product data sheet050308Product data sheet050303Product specification011010Product specification030206Product specification	Section 2 "Pinning information": updated         Table 6 and 7: updated according to latest measurement         Figure 1, 2, 4, 5, 7 to 9, 15, 17 and 18: updated         Figure 3, 6, 10 to 14: added         Section 8 "Test information": added         Section 10 "Packing information": updated         Section 11 "Soldering": added         Section 13 "Legal information": updated         070622       Product data sheet         070622       Product data sheet         050308       Product data sheet         050303       Product specification         011010       Product specification         030206       Product specification			

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### **13. Legal information**

#### 13.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <a href="http://www.nxp.com">http://www.nxp.com</a>.

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